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The CID Number appears on each page of the manuscript. The complete citation is used on the first page, and an abbreviated version on subsequent pages.

Contents

- v Authors
- vii Conference Committee
- ix Nano-bio-optomechanics: nanoaperture tweezers probe single nanoparticles, proteins, and their interactions (Plenary Paper) [9544-501]

1D GROWTH AND DEVICES I

- 9553 02 Using electric field manipulation to fabricate nanoscale fibers on large areas: a path to electronic and photonic devices (Invited Paper) [9553-1] 9553 03 Structural modulation of nanowire interfaces grown over selectively disrupted single crystal surfaces [9553-2] 9553 06 On the MOVPE growth and luminescence properties of GaAs-AlGaAs core-multishell nanowire quantum structures (Invited Paper) [9553-5] 9553 07 Absorption enhancement and carrier diffusion in single lead sulfide nanowire Schottky solar cells (Invited Paper) [9553-6] **1D GROWTH AND DEVICES II** 9553 08 Ordered arrays of bottom-up III-nitride core-shell nanostructures (Invited Paper) [9553-7] 1D MATERIALS AND DEVICES III 9553 OE Sonochemically grown 1D ZnO nanostructures and their applications (Invited Paper) [9553-13] **OD MATERIALS AND DEVICES** 9553 OI Resonant spectroscopy of individual CdSe quantum dots containing single Mn²⁺ ions in (Zn,Cd)Se barrier [9553-17] 9553 OK HgTe colloidal quantum dot LWIR infrared photodetectors [9553-19] 2D MATERIALS AND DEVICES I
 - 9553 OR Functional inks of graphene, metal dichalcogenides and black phosphorus for photonics and (opto)electronics (Invited Paper) [9553-26]

2D MATERIALS AND DEVICES II

- 9553 0S Synthesis of one-dimentional nanostructures for gas sensing and photovoltaic applications (Invited Paper) [9553-27]
- 9553 OT Flexible and stackable non-volatile resistive memory for high integration (Invited Paper) [9553-28]

LOW-D OPTOELECTRONICS

9553 0Z Engineering heterojunctions with carbon nanostructures: towards high-performance optoelectronics (Invited Paper) [9553-34]

NOVEL LOW-D STRUCTURES

- 9553 13 Chemical modification approaches for improved performance of Na-ion battery electrodes [9553-38]
- 9553 14 Deposition and characterizations of ultrasmooth silver thin films assisted with a germanium wetting layer [9553-39]
- 9553 16 High throughput screening of substrates for synthesis and functionalization of 2D materials [9553-41]

POSTER SESSION

9553 18 Fatigue analysis of chevron structures with Z shape arms [9553-43]

Authors

Numbers in the index correspond to the last two digits of the six-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first four digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Ali, Shawkat, OT Andriolo, Jessica M., 02 Atalay, Ramazan, OE Bae, Jinho, OT Bala, Rukayya K., OE Balakrishnan, Ganesh, 08 Bayam, Yavuz, OE Beisel, Josh D., 02 Brueck, S. R. J., 08 Bryant, Benjamin N., 08 Byles, Bryan, 13 Cabello Ruiz, Ramón, 18 Caha, Ihsan, OE Ciani, A., OK Clites, Mallory, 13 Davydov, Albert V., 16 Diaz Leon, Juan J., 14 Duyar, Sinem, OE Eller, Rhett F., 08 Escobedo Alatorre, J. Jesus, 18 Fairchild, Michael N., 08 Feezell, Daniel F., 08 Franson, Marvin J., 02 Fryauf, David M., 14 Garratt, E., 03 Garrett, Matthew, 14 Gordon, Reuven, ix Grein, C., 0K Gültekin, Burak, OE Guyot-Sionnest, P., OK Hasan, Tawfique, OR Hennig, Richard G., 16 Hill, Bryce E., 02 Howe, Richard C. T., OR Hu, Guohua, OR Hyatt, Steven, 07 Islam, M. Saif, OS Islam, Saif M., 14 Karaagac, Hakan, OS Kobayashi, Nobuhiko P., 14 Kooistra-Manning, Emily A., 02 Kyeremateng, Jerry, 02 Lee, Chong Hyun, OT Lovergine, Nico, 06 Loyola, Bryan R., 02 Marzo, Fabio, 06 Mathew, Kiran, 16 Murphy, John P., 02 Nami, Mohsen, 08

Nikoobakht, B., 03 Ocampo Diaz, Alejandra, 18 Okur, Salih, OE Okyay, Tugba O., OE Özbek, Cebrail, OE Peksu, Elif, OS Peng, Xingyue, 07 Pimpinella, R. E., OK Piwowar, Justyna, Ol Pomerantseva, Ekaterina, 13 Prete, Paola, 06 Purkett, Lance M., 02 Rishinaramangalam, Ashwin K., 08 Rodrigues, Debora, OE Rodriguez Ramirez, J. Alfredo, 18 Rosato, Roberta, 06 Ross, Brandon M., 02 Shima, Darryl M., 08 Singh, Arunima K., 16 Skinner, Jack L., 02 Stevanato, Elena, 06 Tavazza, Francesca, 16 Tecpoyotl Torres, Margarita, 18 Tural, Enis E., OE Vera Dimas, J. Gerardo, 18 VJ, Logeeswaran, 14 Wu, Judy Z., OZ Yang, Yiming, 07 Yang, Zongyin, OR Yu, Dong, 07 Zafer, Ceylan, 0E Zhang, Junce, 14

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- 1D Growth and Devices I
 Nobuhiko P. Kobayashi, University of California, Santa Cruz (United States)
 M. Saif Islam, University of California, Davis (United States)
- 2 1D Growth and Devices II
 A. Alec Talin, Sandia National Laboratories (United States)
- 3 1D Materials and Devices III **Paola Prete**, Istituto per la Microelettronica e Microsistemi (Italy)
- 4 Low-D Structures and Characterization **François Léonard**, Sandia National Laboratories (United States)
- 5 OD Materials and Devices **Arunima Singh**, National Institute of Standards and Technology (United States)
- 6 2D Materials and Devices I
 M. Saif Islam, University of California, Davis (United States)
 A. Alec Talin, Sandia National Laboratories (United States)
- 7 2D Materials and Devices II
 Sharka M. Prokes, U.S. Naval Research Laboratory (United States)
 Babak Nikoobakht, National Institute of Science and Technology (United States)
- 8 Low-D Optoelectronics
 Marcus Mueller, Otto-von-Guericke-Universität Magdeburg (Germany)
 Nobuhiko P. Kobayashi, University of California, Santa Cruz (United States)
- 9 Novel Low-D Structures
 Daniel V. Esposito, Columbia University (United States)
 Lan Fu, The Australian National University (Australia)